

Compact Photoelectric Sensor

The CX-400 series of photoelectric sensors is a wide-ranging lineup of 116 different models. Whatever your application entails, SUNX has covered it with this series. Built to IP-67 standards, the CX-400 series is designed for the most demanding environments.

There are also models that are specifically design for resistance to oil, coolant, or ethanol. Couple this with high electrical noise resistance and a built in interference prevention function, and you have one of the most robust sensors on the market.

The CX-400 series is compact in size (W11.2mm x H31.0mm x D20.0mm) with a world standard mounting pitch of 25.4mm. Wiring options include a M8 quick disconnect, M12 quick disconnect, or built-in wire type with a length of 0.5mm, 2m, or 5m.

High precision optics as well as high performance circuitry provides extremely stable sensing for determining small height differences, detecting transparent objects, and subtle color differences. Also, the series offers a high luminance beam spot that achieves long distances and can be as small as 2mm in diameter for detection of minute objects.

Four sensing types are available:

Diffuse Reflective

Available in 100, 300, and 800mm detecting distance models, along with a narrow view type that has a 2mm diameter beam spot.

Thru-beam

Available in 10m and a longest in its class 15m detecting distance models. The ultra long range 15m version is made possible by utilizing a powerful infrared LED light source which is great for powering through dust and dirt as well.

• Retro-Reflective

Standard models are available in 3 and 5m detecting distance types. Specialized models for transparent object detection are also available in 0.5 and 2m detecting distances.

Adjustable Range Reflective

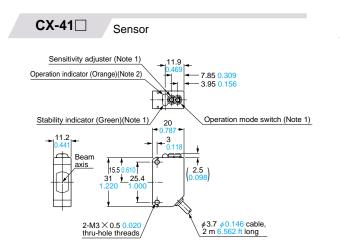
Available in 50, 100, and 300m detecting distance models, with the addition of a 2mm diameter small beam spot type. These sensors also incorporate foreground suppression and background suppression functions to limit the effect of unwanted detection.

All types are available with NPN or PNP transistor outputs.

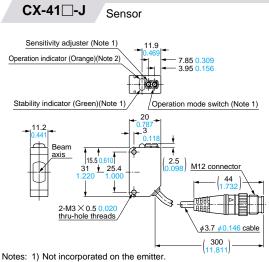
Model Name	Model Pic	Туре	Output Operation	Output Configuration	Emitting Element	Max. Range (mm)	Max. Range (in)
Sort 🔺 🔻		Sort 🔺 💙	Sort 🔺 🔻	Sort 🔺 💙	Sort 🔺 🔻	Sort 🔺 🔻	Sort 🔺 🔻
CX-411		Thrubeam	Light-ON/Dark- ON	NPN	Red LED	10000	393.7
CX-411-J		Thrubeam, M12 Quick Disconnect	Light-ON/Dark- ON	NPN	Red LED	10000	393.7
СХ-411-Р		Thrubeam	Light-ON/Dark- ON	PNP	Red LED	10000	393.7

CX-400

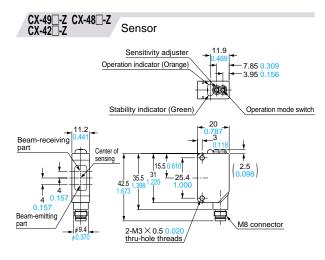
DIMENSIONS (Unit: mm in)

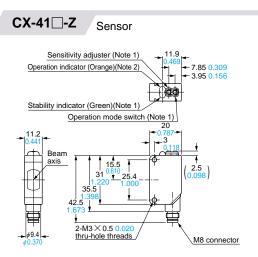


Notes: 1) Not incorporated on the emitter. 2) It is the power indicator (green) on the emitter.

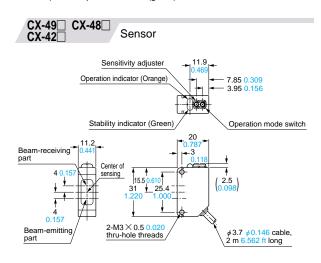


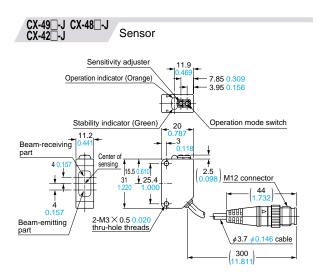
2) It is the power indicator (green) on the emitter.





Notes: 1) Not incorporated on the emitter. 2) It is the power indicator (green) on the emitter.







SPECIFICATIONS

Туре		Thru-beam		Retroreflective				Diffuse reflective				
			Long sensing range	With polarizing filters	Long sensing range	For transparent	t object sensing		Dilluse	enective	Narrow-view	
	2 Ž	NPN output	CX-411	CX-412	CX-491	CX-493	CX-481	CX-482	CX-424	CX-421	CX-422	CX-423
lter	Model No.	PNP output	CX-411-P	CX-412-P	CX-491-P	CX-493-P	CX-481-P	CX-482-P	CX-424-P	CX-421-P	CX-422-P	CX-423-P
Ser	nsing range		10 m 32.808 ft	15 m 49.213 ft	3 m 9.843 ft (Note 1)	5 m 16.404 ft (Note 1)	50 to 500 mm 1.969 to 19.685 in (Note 1)	0.1 to 2 m 0.328 to 6.562 ft (Note 1)	100 mm 3.937 in (Note 2)	300 mm 11.811 in (Note 2)	800 mm 31.496 in (Note 2)	70 to 200 mm 2.756 to 7.874 in (Note 2
Sensing object		or more o	φ 12 mm φ0.472 in or more opaque object (Note 3) ^{\$50} mm φ1.969 in or more opaque, translucent or specular object (Note 1) ^{\$50} mm φ1.969 in or more opaque or translucent opaque or translucent opaque or translucent opaque opaque, (Note 1) ^{\$50} mm φ1.969 in or more opaque or translucent opaque or opaque object (Note 1)					Opaque, translucent or or transpare transparent object (Min.sensing di)			Opaque, translucer or transparent obje (Min. sensing object: \$0.5 n \$0.020 in copper wire	
Hys	steresis			15 % or less of operation distance							ance	
Repe	atability (perpend	licular to sensing axis)	0.5 mm 0.020 in or less						1 m	m 0.039 in or	less	0.5 mm 0.020 in or le
Sup	oply voltage		12 to 24 V DC \pm 10 % Ripple P-P 10 % or less									
Cur	rent consum	nption		Emitter: 25 mA or less Receiver: 20 mA or less							3	20 mA or les
Out	put		• Max • Appl	en-collector tra imum sink cur lied voltage: 3 dual voltage:	rent: 100 mA 0 V DC or les	t 100 mA sink		• Maxi • Appli	n-collector tra mum source ied voltage: 3 dual voltage:	nsistor current: 100 m 0 V DC or less 1 V or less (at 0.4 V or less (a	s (between ou 100 mA source	ce current)
	Output ope	eration	Switchable either Light-ON or Dark-ON									
Short-circuit protection			Incorporated									
Response time		1 ms or less										
Operation indicator			Orange LED (lights up when the output is ON)(incorporated on the receiver for thru-beam type)									
Sta	bility indicate	or	Green LED	(lights up und	ler stable ligh	t received co	ndition or stat	ole dark condi	tion)(incorpo	rated on the r	eceiver for th	ru-beam type
Power indicator			Green LED (lights up when the power is ON) (incorporated on the emitter)									
Ser	nsitivity adju	ster			Continuousl	y variable ac	ljuster (incorp	orated on the	receiver for t	hru-beam type	e)	
Automatic interference prevention function		Two units of sersors can be mounted close Incorporated (Two units of sensors can be mounted close together.) Upgefor with indefence tange 5m (5.49.4) Incorporated (Two units of sensors can be mounted close together.)										
	Protection		IP67 (IEC)									
Ambient temperature			- 25 to	+55 ℃ -1	3 to + 131 °I	= (No dew co	ndensation o	r icing allowe	d), Storage:	-30 to +7	$70 ^{\circ}\mathrm{C} - 22 ^{\circ}\mathrm{tc}$	o +158 °F
Ambient humidity Ambient illuminance			35 to 85 % RH, Storage: 35 to 85 % RH									
resis	Ambient ille	uminance	Sunlight:10,000 ℓx at the light-receiving face, Incandescent light: 3,000 ℓx at the light-receiving face									
	EMC						EN 60	947-5-2				
ronmental	Voltage wit	hstandability	1,000 V AC for one min. between all supply terminals connected together and enclosure									
Enviro	Insulation r	esistance	20 M Ω , or more, with 250 V DC megger between all supply terminals connected together and enclosure									
ш	Vibration re	esistance	10 to 500 Hz frequency, 1.5 mm 0.059 in double amplitude (10 G max.) in X, Y and Z directions for two hours							s each		
	Shock resi	stance	500 m/s ² acceleration (50 G approx.) in X, Y and Z directions for three times each									
Emitting element (modulated) Red LED Infrared LED Red LED Infrared LED							Red LED					
Mat	terial		Enclosure: F	PBT (polybuty	lene terepht	nalate), Lens:	acrylic (CX-4	18: polycarb	onate), Front	cover: acrylic	c (CX-48 ⊡: p	olycarbonate
Cat	ble			().2 mm ² 3-co	re (thru-bean	n type emitte	r: 2-core) cab	tyre cable, 2	m 6.562 ft lo	ng	
Cat	ole extensior	n	Extensio	n up to total 1	100 m <u>328.08</u>	84 ft is possib	le with 0.3 m	m ² , or more,	cable (thru-b	eam type: bo	oth emitter an	d receiver)
We	ight				:	50 g approx.	(Emitter of th	ru-beam type	: 45 g appro	x.)		
-	essories					RF-230 (Re	() () - (

Sensing					
range: A		CX-491	CX-493	CX-481	CX-482
Sensing object	А	3 m 9.843 ft		50 to 500 mm 1.969 to 19.685 in	0.1 to 2 m 0.328 to 6.562 ft
Setting range				100 to 500 mm 3.937 to 19.685 in	

Sensor Reflector

2) The sensing range of the diffuse reflective type sensor is specified for white non-glossy paper ($200 \times 200 \text{ mm } 7.874 \times 7.874 \text{ in}$) as the object. 3) If slit masks (optional) are fitted, an object of $\phi 0.5 \text{ mm } \phi 0.020 \text{ in}$ (using round slit mask) can be detected.

SPECIFICATIONS

NPN output PNP output range (Note 1) (with white non-glossy paper) (with white non-glossy	<npn output="" type=""> NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or Ik</npn>	2 % or less of operation distance 2 % or less, Perpendicular to ser 12 to 24 V DC ± 10 % 25 mA 00 mA or less (between output and 0 V) ses (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	nsing axis: 0.2 mm 0.008 in or les Ripple P-P 10 % or less A or less <pnp output="" type=""> PNP open-collector transistor · Maximum source current: · Applied voltage: 30 V DC or · Residual voltage: 1 V or le 0.4 V or tion-ON or Detection-OFF porated or less o when the output is ON)</pnp>	20 to 300 mm 0.787 to 11.811 in 5 % or less of operation distance s (with white non-glossy paper					
t operation circuit protection time indicator djuster	20 to 50 mm 0. 2 to 50 mm 0.0 2 to 50 mm 0.0 Along sensing axis: 1 mm 0.033 <npn output="" type=""> NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or tk</npn>	787 to 1.969 in 7787 to 1.969 in 2 % or less of operation distance 9 in or less, Perpendicular to ser 12 to 24 V DC ± 10 % 25 mA 10 mA or less (between output and 0 V) ass (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	20 to 100 mm 0.787 to 3.937 in 15 to 100 mm 0.591 to 3.937 in 15 to 100 mm 0.591 to 3.937 in ansing axis: 0.2 mm 0.008 in or less Ripple P-P 10 % or less A or less <pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 30 V DC o • Residual voltage: 1 V or le 0.4 V or ttion-ON or Detection-OFF porated or less o when the output is ON)</pnp>	40 to 300 mm 1.575 to 11.811 i 20 to 300 mm 0.787 to 11.811 ii 5 % or less of operation distance s (with white non-glossy paper (with white non-glossy paper) 100 mA or less (between output and + V) ss (at 100 mA source current)					
t operation circuit protection time indicator djuster	2 to 50 mm 0.0 Along sensing axis: 1 mm 0.039 <npn output="" type=""> NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or Ik</npn>	2 % or less of operation distance 2 % or less, Perpendicular to ser 12 to 24 V DC ± 10 % 25 mA 00 mA or less (between output and 0 V) ses (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	15 to 100 mm 0.591 to 3.937 in ansing axis: 0.2 mm 0.008 in or less Ripple P-P 10 % or less A or less <pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC of • Residual voltage: 1 V or le 0.4 V or etion-ON or Detection-OFF porated • or less • owhen the output is ON)</pnp>	20 to 300 mm 0.787 to 11.811 ii 5 % or less of operation distance s (with white non-glossy paper 100 mA or less (between output and + V) ss (at 100 mA source current)					
it operation circuit protection time indicator djuster	Along sensing axis: 1 mm 0.033 NPN output type> NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or letage:	2 % or less of operation distance a) in or less, Perpendicular to ser 12 to 24 V DC ± 10 % 25 mA 10 mA or less (between output and 0 V) ses (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	s nsing axis: 0.2 mm 0.008 in or less Ripple P-P 10 % or less A or less <pnp output="" type=""> PNP open-collector transistor · Maximum source current: · Applied voltage: 30 V DC o · Residual voltage: 1 V or le 0.4 V or tion-ON or Detection-OFF porated or less o when the output is ON)</pnp>	5 % or less of operation distance s (with white non-glossy paper 100 mA or less (between output and + V) ss (at 100 mA source current)					
ity tage nsumption t operation circuit protection time indicator dicator djuster	<npn output="" type=""> NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or Ik</npn>	P in or less, Perpendicular to ser 12 to 24 V DC ± 10 % 25 mA 10 mA or less (between output and 0 V) ess (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	nsing axis: 0.2 mm 0.008 in or les Ripple P-P 10 % or less A or less <pnp output="" type=""> PNP open-collector transistor · Maximum source current: · Applied voltage: 30 V DC or · Residual voltage: 1 V or le 0.4 V or tion-ON or Detection-OFF porated or less o when the output is ON)</pnp>	s (with white non-glossy paper s (with white non-glossy paper of loss (between output and + V) ss (at 100 mA source current)					
tage nsumption t operation circuit protection time indicator dicator djuster	<npn output="" type=""> NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or Ik</npn>	12 to 24 V DC ± 10 % 25 mA 0 mA or less (between output and 0 V) ess (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	Ripple P-P 10 % or less A or less <pnp output="" type=""> PNP open-collector transistor · Maximum source current: · Applied voltage: 30 V DC of · Residual voltage: 1 V or le 0.4 V or tion-ON or Detection-OFF porated or less o when the output is ON)</pnp>	100 mA or less (between output and + V) ss (at 100 mA source current)					
t operation circuit protection time indicator djuster	NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or le	25 mA or less (between output and 0 V) ess (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	A or less <pnp output="" type=""> PNP open-collector transistor · Maximum source current: · Applied voltage: 30 V DC of · Residual voltage: 1 V or le 0.4 V or ttion-ON or Detection-OFF porated or less o when the output is ON)</pnp>	or less (between output and $+V$) ss (at 100 mA source current)					
t operation circuit protection time indicator dicator djuster	NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or le	0 mA or less (between output and 0 V) ess (at 100 mA sink current) less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	<pnp output="" type=""> PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC o • Residual voltage: 1 V or le 0.4 V or tition-ON or Detection-OFF porated or less o when the output is ON)</pnp>	or less (between output and $+V$ ss (at 100 mA source current)					
circuit protection time indicator dicator djuster	NPN open-collector transistor • Maximum sink current: 10 • Applied voltage: 30 V DC • Residual voltage: 1 V or le	or less (between output and 0 V) ess (at 100 mA sink current) r less (at 16 mA sink current) Switchable either Detect Incorp 1 ms Orange LED (lights up	PNP open-collector transistor • Maximum source current: • Applied voltage: 30 V DC of • Residual voltage: 1 V or le 0.4 V or tion-ON or Detection-OFF porated • or less • when the output is ON)	or less (between output and $+V$ ss (at 100 mA source current)					
circuit protection time indicator dicator djuster		Incorp 1 ms Orange LED (lights up	porated or less o when the output is ON)						
time indicator dicator djuster		1 ms Orange LED (lights up	or less when the output is ON)						
indicator dicator djuster		Orange LED (lights up	when the output is ON)						
dicator djuster			. ,						
djuster		Green LED (lights up under sta	able operating condition) (Note 2)						
			Green LED (lights up under stable operating condition) (Note 2)						
ode	5-turn mechanical adjuster								
000	BGS /	FGS functions Switchable with	n wiring of sensing mode selectior	n input					
rence prevention function (Note 3)	Incorporated								
ction	IP67 (IEC)								
ent temperature	-25 to $+55$ °C -13 to $+131$ °F (No dew condensation or icing allowed), Storage: -30 to $+70$ °C -22 to $+158$ °F								
ent humidity	35 to 85 % RH, Storage: 35 to 85 % RH								
ent illuminance	Sunlight:10,000 ℓ x at the light-receiving face, Incandescent light: 3,000 ℓ x at the light-receiving face								
	EN 60947-5-2								
e withstandability	1,000 V AC for one min. between all supply terminals connected together and enclosure								
tion resistance	20 M Ω , or more, with 250 V DC megger between all supply terminals connected together and enclosure								
ion resistance	10 to 500 Hz frequency, 3 mm 0.118 in double amplitude in X, Y and Z directions for two hours each								
resistance	500 m/s ² acceleration (50 G approx.) in X, Y and Z directions for three times each								
ement	Red LED (modulated)								
eter	ϕ 2 mm ϕ 0.079 in approx. (at 50 mm 1.969 in distance)	ϕ 6.5 mm ϕ 0.256 in approx. (at 50 mm 1.969 in distance)		□15 mm □0.591 in approx. (at 300 mm 11.811 in distance					
	Enclosure: PBT (Polybutylene terephthalate), Front cover: Polycarbonate, Indicator cover: Polycarbonate								
		0.2 mm ² 4-core cabtyre	e cable, 2 m 6.562 ft long						
nsion	Extensi	on up to total 100 m 328.084 ft	is possible with 0.3 mm ² , or more	, cable.					
		55 g a	approx.						
	e withstandability on resistance resistance ment ter esion e adjustable range tance adjuster. The	tilluminance Sunlight:10,000 ℓ e withstandability 1,000 V AC on resistance 20 MΩ, or more, with on resistance 10 to 500 Hz freq resistance 500 m/s² mment $\phi 2 \text{ mm} \phi 0.079 \text{ in approx.} (at 50 \text{ mm 1.969 in distance)} Enclosure: PBT (Position) Enclosure: PBT (Position) asion Extensi e adjustable range stands for the maximum sensire $	tilluminanceSunlight:10,000 ℓ x at the light-receiving face, IncEN 60EN 60e withstandability1,000 V AC for one min. between all supplyon resistance20 MΩ, or more, with 250 V DC megger between aon resistance10 to 500 Hz frequency, 3 mm 0.118 in double atresistance500 m/s² acceleration (50 G approx.) inmentRed LEDter ϕ 2 mm ϕ 0.079 in approx. (at 50 mm 1.969 in distance)Enclosure: PBT (Polybutylene terephthalate), Front 0.2 mm² 4-core cabtyrsionExtension up to total 100 m 328.084 ft55 ge adjustable range stands for the maximum sensing range which can be set w tance adjuster. The sensor can detect an object 2 mm 0.079 in [CX-444(-P):	tilluminance Sunlight:10,000 ℓ x at the light-receiving face, Incandescent light: 3,000 ℓ x at the I EN 60947-5-2 ewithstandability 1,000 V AC for one min. between all supply terminals connected together an on resistance 20 MΩ, or more, with 250 V DC megger between all supply terminals connected together an on resistance 10 to 500 Hz frequency, 3 mm 0.118 in double amplitude in X, Y and Z directions for tresistance 500 m/s² acceleration (50 G approx.) in X, Y and Z directions for three time ment Red LED (modulated) ter					

3) Note that detection may be unstable depending on the mounting conditions or the sensing object. In the state that this product is mounted, be sure to check the operation with the actual sensing object.

	of the sensor: A	
٦	Adjustable range: B	
ھ		Sensing object

CX-441 /443	CX-444	CX-442
2 to 50 mm 0.079 to 1.969 in		20 to 300 mm 0.787 to 11.811 in
20 to 50 mm 0.787 to 1.969 in		40 to 300 mm 1.575 to 11.811 in